Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



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SHAY

PRIMARY CHARACTERISTICS					
I _{F(AV)} 10 A					
V _R	1000 V, 1200 V				
V _F at I _F	1.33 V				
I _{FSM}	140 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Snap factor	0.6				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES U						
V _{RRM}		1000 to 1200	V				
I _{F(AV)}	Sinusoidal waveform	10	٨				
I _{FSM}		140	— A				
t _{rr}	1 A, 100 A/μs	80	ns				
V _F	10 A, T _J = 25 °C	1.33	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-10ETF10-M3	1000	1100	4
VS-10ETF12-M3	1200	1200	4

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_C = 125 °C, 180° conduction half sine wave	10			
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	115	А		
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	140			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	66	A ² s		
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	94	A-S		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.33	V	
Forward slope resistance	r _t	T ₁ = 150 °C		22.9	mΩ	
Threshold voltage	V _{F(TO)}	1j = 150 C		0.96	V	
Maximum reverse leakage current	1	$T_J = 25 °C$		0.1	mA	
waximum reverse leakage current	IRM	T _J = 150 °C	V_R = Rated V_{RRM}	4	IIIA	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	In at 10 Anis	310	ns			
Reverse recovery current	I _{rr}	l _F at 10 A _{pk} 25 A/µs	4.7	А			
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	dir/Q _{rr}		
Typical snap factor	S		0.6		dt I _{RM(REC)}		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance junction to case	R _{thJC}	DC operation	1.5		
Maximum thermal resistance junction to ambient	R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight			2	g	
Approximate weight			0.07	oz.	
Mounting torque minimum			6 (5)	kgf ⋅ cm	
Mounting torque maximum			12 (10)	(lbf · in)	
Marking device		Case style TO-220AC 2L (JEDEC)	10ETF10 10ETF12		

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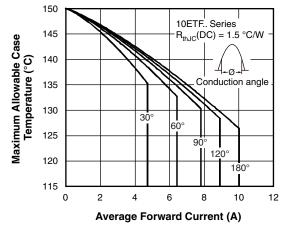


Fig. 1 - Current Rating Characteristics

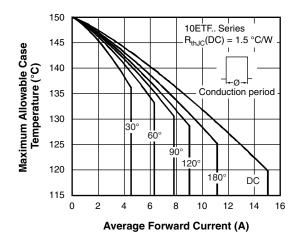


Fig. 2 - Current Rating Characteristics

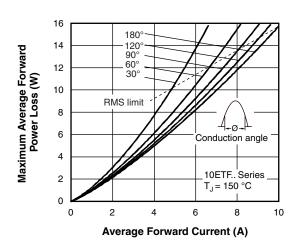


Fig. 3 - Forward Power Loss Characteristics

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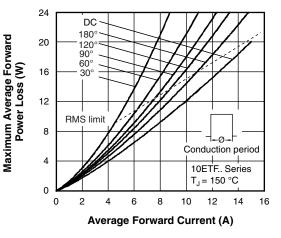


Fig. 4 - Forward Power Loss Characteristics

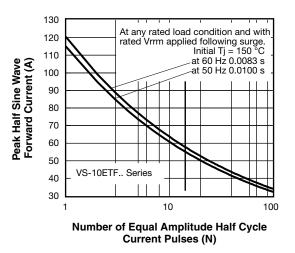


Fig. 5 - Maximum Non-Repetitive Surge Current

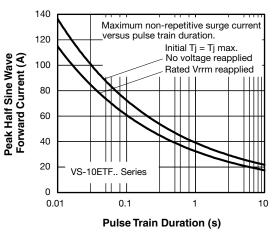


Fig. 6 - Maximum Non-Repetitive Surge Current

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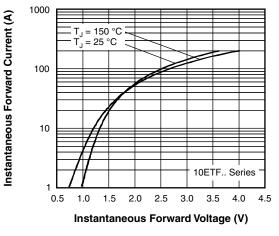


Fig. 7 - Forward Voltage Drop Characteristics

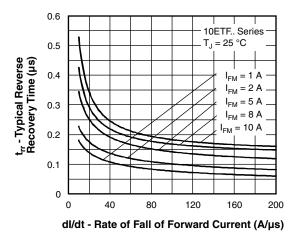


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^\circ C$

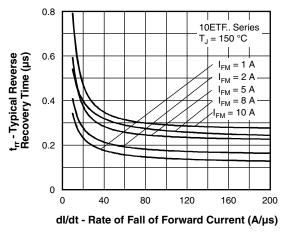


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \ ^\circ C$

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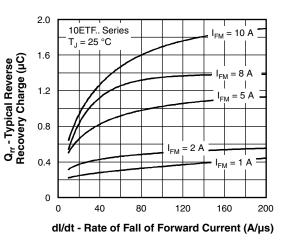


Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \ ^{\circ}C$

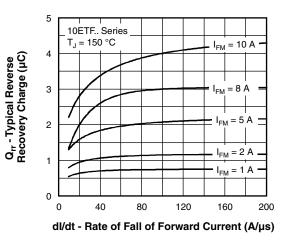


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

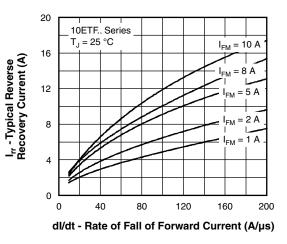


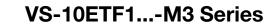
Fig. 12 - Recovery Current Characteristics, $T_J = 25 \ ^{\circ}C$

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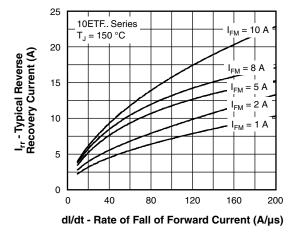


Fig. 13 - Recovery Current Characteristics, $T_J = 150$ °C

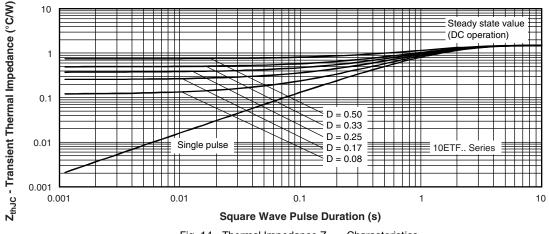


Fig. 14 - Thermal Impedance ZthJC Characteristics

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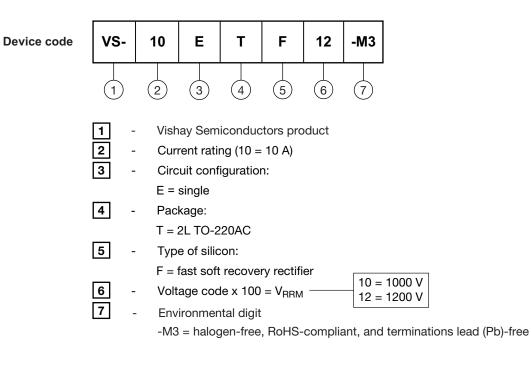


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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)						
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION						
VS-10ETF10-M3	50	Antistatic plastic tube				
VS-10ETF12-M3	50	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391		

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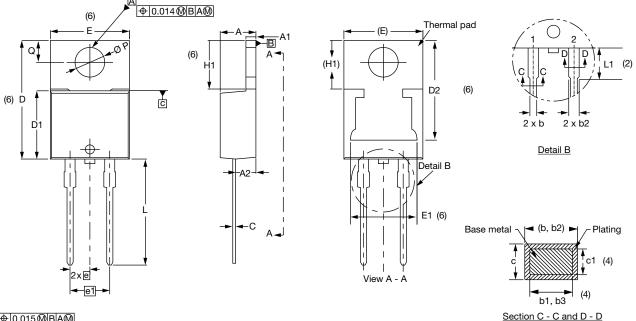
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TO-220AC 2L

DIMENSIONS in millimeters and inches

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⊕0.015@BA@



SYMBOL	MILLIN	MILLIMETERS		INCHES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØΡ	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

Conforms to JEDEC[®] outline TO-220AC

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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